HALOGEN FREE



www.vishay.com

## Vishay General Semiconductor

# SMD Photovoltaic Solar Cell Protection TMBS® (Trench MOS Barrier Schottky) Rectifiers

Ultra Low  $V_F = 0.31 \text{ V}$  at  $I_F = 5 \text{ A}$ 



### **DESIGN SUPPORT TOOLS**





PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	15 A		
V <sub>RRM</sub>	45 V		
I <sub>FSM</sub>	210 A		
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.42 V		
T <sub>J</sub> max.	150 °C		
Package	SMPC (TO-277A)		
Circuit configuration	Single		

#### **FEATURES**

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

## **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V15P45S	UNIT	
Device marking code		1545S		
Maximum repetitive peak reverse voltage	$V_{RRM}$	45	V	
Maximum DC forward current	I <sub>F</sub> <sup>(1)</sup>	15	Α	
	I <sub>F</sub> <sup>(2)</sup>	4.8		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	210	А	
Junction temperature in DC forward current without reverse bias, $t \le 1 \text{ h}$	T <sub>J</sub> <sup>(3)</sup>	≤ 200	°C	
Operating junction temperature range	T <sub>OP</sub>	-40 to +150	°C	
Storage temperature range	T <sub>STG</sub>	-40 to +175	°C	

#### Notes

- (1) Mounted on 30 mm x 30 mm aluminum PCB
- (2) Free air, mounted on recommended copper pad area
- (3) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



# Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT			
Instantaneous forward voltage	$I_F = 5.0 \text{ A}$	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.40	-	V			
	I <sub>F</sub> = 7.5 A			0.45	-				
	I <sub>F</sub> = 15 A			0.49	0.58				
	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 125 °C		0.31	-				
	I <sub>F</sub> = 7.5 A		T <sub>A</sub> = 125 °C	T <sub>A</sub> = 125 °C	T <sub>A</sub> = 125 °C		0.34	-	
	I <sub>F</sub> = 15 A			0.42	0.51				
Reverse current	V <sub>R</sub> = 45 V	$T_A = 25 \degree C$ $T_A = 125 \degree C$	T <sub>A</sub> = 25 °C	-	1500	μΑ			
	v <sub>R</sub> = 45 v		IR (=)	15	50	mA			

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

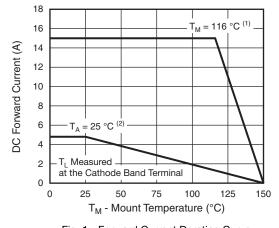
THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V15P45S	UNIT	
Typical thermal registeres	R <sub>0JA</sub> (1)	75	°C/W	
Typical thermal resistance	R <sub>0JM</sub> (2)	4	- C/W	

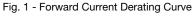
#### Notes

- (1) Free air, mounted on recommended copper pad area; thermal resistance R<sub>0JA</sub> junction to ambient
- (2) Mounted on 30 mm x 30 mm aluminum PCB; thermal resistance R<sub>0,IM</sub> junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V15P45S-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
V15P45S-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





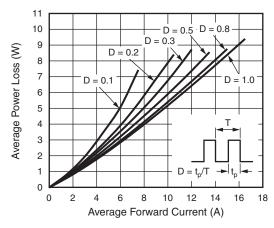


Fig. 2 - Forward Power Loss Characteristics Per Diode

#### Notes

- $^{(1)}$  Mounted on 30 mm x 30 mm aluminum PCB;  $T_M$  measured at the terminal of cathode band ( $R_{\theta JM} = 4$  °C/W)
- <sup>(2)</sup> Free air, mounted on recommended copper pad area ( $R_{\theta JA} = 75 \, ^{\circ}\text{C/W}$ )



# Vishay General Semiconductor

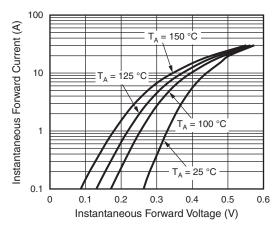


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

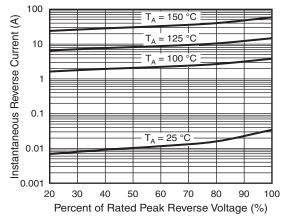


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

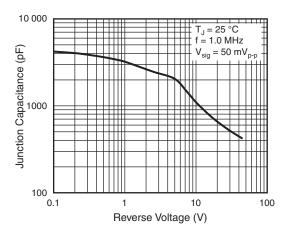


Fig. 5 - Typical Junction Capacitance

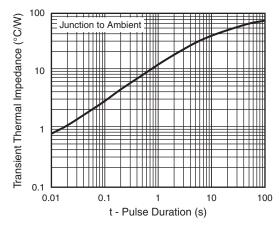
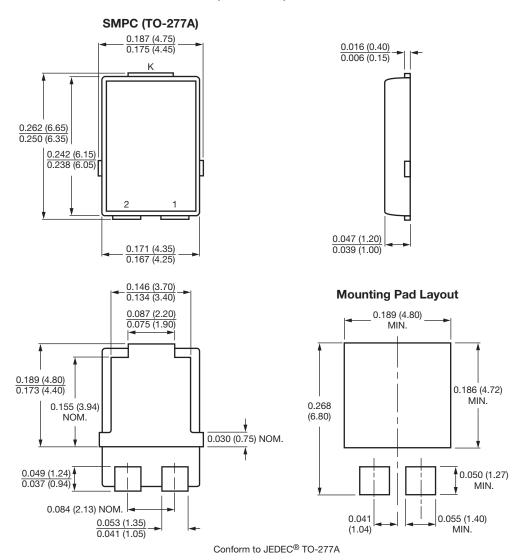


Fig. 6 - Typical Transient Thermal Impedance Per Diode



# Vishay General Semiconductor

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





## **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.